NSN 5961-01-170-2169

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-170-2169 **Inclosure Material:** Glass **Overall Length:** 0.375 inches **Terminal Length:** 1.100 inches **Overall Diameter:** 0.205 inches **Function For Which Designed:** Transient suppressor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 33.0 breakdown voltage, dc **Current Rating Per Characteristic:** 1.00 milliamperes collector current, dc peak **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector absolute **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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